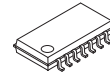


## 14μA/ch, 16V Operation, Rail-to-Rail Output Quad CMOS Operational Amplifier

### ■GENERAL DESCRIPTION

The NJU7068 is a low power, high Voltage operation, quad CMOS Operational Amplifier. It is tolerant to RF noise. The NJU7068 can operate wide voltage range from single-supply voltage of +4V to +16V. In addition, this amplifier features Rail-to-Rail output and low input bias current (1pA typ.). Because of these features, the NJU7068 is ideal for low side current sense amplifier.

### ■PACKAGE OUTLINE



**NJU7068M**  
(DMP14)



**NJU7068V**  
(SSOP14)

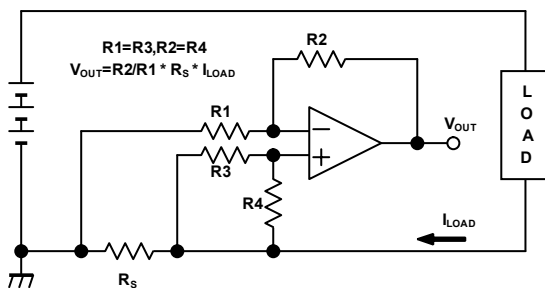
### ■FEATURES

- |                             |   |
|-----------------------------|---|
| ●Low Supply Current         | 14μA/ch typ. (at $V_{DD}=+5V$ ), 16.5μA/ch typ. (at $V_{DD}=+15V$ ) |
| ●Rail-to-Rail Output        | GND + 0.05V to $V_{DD} - 0.1V$ min. ( $R_L=10k\Omega$ to 0V)        |
| ●Wide Operating Voltage     | $V_{opr}= 4V$ to 16V  |
| ●Input Offset Voltage       | $V_{IO}=4mV$ max.   |
| ●Low Input Bias Current     | 1pA typ.  |
| ●Slew Rate                  | 0.04V/μs typ.   |
| ●Gain Bandwidth Product     | 90kHz   |
| ●Enhanced RF Noise Immunity |   |
| ●Package Outline            | DMP14,SSOP14  |
| ●CMOS Process               |   |

### ■APPLICATIONS

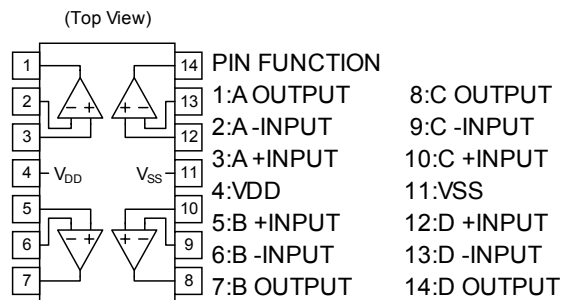
- Battery-operated application
- Battery Monitor
- Current Sensor
- Photodiode application

### ■APPLICATION CIRCUIT



Low-side Current Sensor

### ■PIN CONFIGURATION



## ■ABSOLUTE MAXIMUM RATINGS

(Ta=25°C, unless otherwise noted.)

| PARAMETER                   | SYMBOL    | RATING  | UNIT |
|-----------------------------|-----------|---|------|
| Supply Voltage              | $V_{DD}$  | +18   | V    |
| Common Mode Input Voltage   | $V_{IC}$  | $V_{SS} - 0.3$ to $V_{DD} + 0.3$              | V    |
| Differential Input Voltage  | $V_{ID}$  | ±18 (Note 1)                                  | V    |
| Power Dissipation           | $P_D$     | [DMP14]500 (Note2,3)<br>[SSOP14]450 (Note2,3) | mW   |
| Operating Temperature Range | $T_{opr}$ | -40 to +85                                    | °C   |
| Storage Temperature Range   | $T_{stg}$ | -55 to +150                                   | °C   |

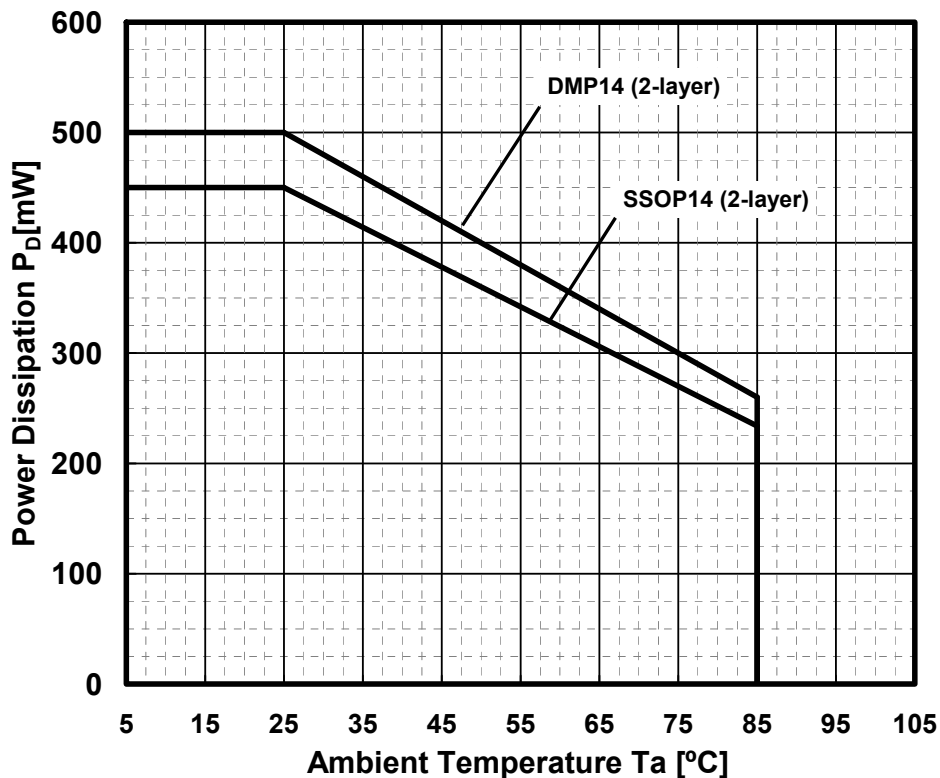
(Note 1) For supply voltage less than +18V, the absolute maximum rating is equal to the supply voltage.

(Note 2) EIA/JEDEC STANDARD Test board (76.2x114.3x1.6mm, 2layer, FR-4) mounting

(Note 3) Do not exceed "Power dissipation: PD" in which power dissipation in IC is shown by the absolute maximum rating.

See Figure "Power Dissipation Curve" when ambient temperature is over 25°C.

**Figure1.Power Dissipation Derating Curve**



## ■RECOMMENDED OPERATING CONDITION

(Ta=25°C)

| PARAMETER      | SYMBOL   | RATING    | UNIT |
|----------------|----------|-----------|------|
| Supply Voltage | $V_{DD}$ | +4 to +16 | V    |

**■ ELECTRICAL CHARACTERISTICS**
**● DC CHARACTERISTICS**

 ( $V_{DD}=5V, V_{SS}=0V, T_a=25^{\circ}C$ , unless otherwise noted.)

| PARAMETER                       | SYMBOL                   | TEST CONDITION                            | MIN. | TYP. | MAX. | UNIT              |
|---------------------------------|--------------------------|---|------|------|------|-------------------|
| Supply Current                  | $I_{DD}$                 | No Signal                                 | -    | 56   | 96   | $\mu A$           |
| Input Offset Voltage            | $V_{IO}$                 | $V_{IC}=0V, R_S=50\Omega$                 | -    | 1    | 4    | mV                |
| Input Offset Voltage Drift      | $\Delta V_{IO}/\Delta T$ | $T_a = -40^{\circ}C$ to $+85^{\circ}C$    | -    | 3.3  | -    | $\mu V/^{\circ}C$ |
| Input Bias Current              | $I_B$                    | $V_{IC}=0V, R_S=50\Omega$                 | -    | 1    | -    | pA                |
| Input Offset Current            | $I_{IO}$                 | $V_{IC}=0V, R_S=50\Omega$                 | -    | 1    | -    | pA                |
| Large Signal Voltage Gain       | $A_V$                    | $V_O=1V$ to $4V, R_L=10k\Omega$ to $2.5V$ | 90   | 110  | -    | dB                |
| Common Mode Rejection Ratio     | CMR                      | $V_{ICM}=0V$ to $3.4V$                    | 65   | 80   | -    | dB                |
| Supply Voltage Rejection Ratio  | SVR                      | $V_{DD}=4V$ to $16V$                      | 70   | 85   | -    | dB                |
| Maximum Output Voltage 1        | $V_{OH1}$                | $R_L=10k\Omega$ to $2.5V$                 | 4.95 | 4.98 | -    | V                 |
|                                 | $V_{OL1}$                |   | -    | 0.02 | 0.05 |                   |
| Maximum Output Voltage 2        | $V_{OH2}$                | $R_L=10k\Omega$ to $0V$                   | 4.90 | 4.96 | -    | V                 |
|                                 | $V_{OL2}$                |   | -    | 0.01 | 0.05 |                   |
| Maximum Output Voltage 3        | $V_{OH3}$                | $I_{source} = 3mA$                        | 4.65 | 4.75 | -    | V                 |
|                                 | $V_{OL3}$                | $I_{sink} = 3mA$                          | -    | 0.20 | 0.30 |                   |
| Common Mode Input Voltage Range | $V_{ICM}$                | CMR $\geq$ 65dB                           | 0    | -    | 3.4  | V                 |

**● AC CHARACTERISTICS**

 ( $V_{DD}=5V, V_{SS}=0V, T_a=25^{\circ}C$ , unless otherwise noted.)

| PARAMETER                      | SYMBOL   | TEST CONDITION  | MIN. | TYP.  | MAX. | UNIT           |
|--------------------------------|----------|---|------|-------|------|----------------|
| Gain Bandwidth Product         | GBW      | $R_L=10k\Omega$ to $2.5V, C_L=20pF, f=1kHz$   | -    | 60    | -    | kHz            |
| Phase Margin                   | $\phi_M$ | $R_L=10k\Omega$ to $2.5V, C_L=20pF$   | -    | 75    | -    | deg            |
| Gain Margin                    | $G_M$    | $R_L=10k\Omega$ to $2.5V, C_L=20pF$   | -    | 22    | -    | dB             |
| Equivalent Input Noise Voltage | $V_{NI}$ | $f=1kHz$  | -    | 45    | -    | $nV/\sqrt{Hz}$ |
| Channel Separation             | CS       | $f=1kHz$  | -    | 120   | -    | dB             |
| Slew Rate                      | SR1      | $G_V=0dB, R_L=10k\Omega$ to $2.5V, C_L=20pF, V_{in}=1V_{pp}$ (2V to 3V)<br>(Note 4)               | -    | 0.03  | -    | V/ $\mu s$     |
|                                | SR2      | $G_V=0dB, R_L=10k\Omega$ to $0V, C_L=20pF, V_{in}=1V_{pp}$ (2V to 3V)<br>(Note 4)                 | -    | 0.03  | -    |                |
| Power Band                     | PBW1     | $G_V=+6dB, R_L=10k\Omega$ to $2.5V, C_L=20pF, V_{in}=2.5V_{pp}$ (1.25V to 3.75V), $V_o>4.8V_{pp}$ | -    | 3.6   | -    | kHz            |
|                                | PBW2     | $G_V=+6dB, R_L=10k\Omega$ to $0V, C_L=20pF, V_{in}=2.5V_{pp}$ (1.25V to 3.75V), $V_o>4.8V_{pp}$   | -    | 3.2   | -    |                |
| Total Harmonic Distortion      | THD1     | $G_V=+6dB, R_L=10k\Omega$ to $2.5V, C_L=20pF, f=100Hz, V_{out}=2V_{pp}$                           | -    | 0.05  | -    | %              |
|                                | THD2     | $G_V=+6dB, R_L=10k\Omega$ to $0V, C_L=20pF, f=100Hz, V_{out}=2V_{pp}$                             | -    | 0.005 | -    | %              |

(Note 4) Slew rate is defined by the lower value of the rise or fall.

**■ ELECTRICAL CHARACTERISTICS**
**● DC CHARACTERISTICS**

 (V<sub>DD</sub>=10V, V<sub>SS</sub>=0V, Ta=25°C, unless otherwise noted.)

| PARAMETER                       | SYMBOL               | TEST CONDITION                                       | MIN. | TYP. | MAX. | UNIT  |
|---------------------------------|----------------------|--|------|------|------|-------|
| Supply Current                  | I <sub>DD</sub>      | No Signal  | -    | 62   | 114  | μA    |
| Input Offset Voltage            | V <sub>IO</sub>      | V <sub>IC</sub> = 0V, R <sub>S</sub> =50Ω            | -    | 1    | 4    | mV    |
| Input Offset Voltage Drift      | ΔV <sub>IO</sub> /ΔT | Ta = -40°C to +85°C                                  | -    | 2.7  | -    | μV/°C |
| Input Bias Current              | I <sub>B</sub>       | V <sub>IC</sub> = 0V, R <sub>S</sub> =50Ω            | -    | 1    | -    | pA    |
| Input Offset Current            | I <sub>IO</sub>      | V <sub>IC</sub> = 0V, R <sub>S</sub> =50Ω            | -    | 1    | -    | pA    |
| Large Signal Voltage Gain       | A <sub>V</sub>       | V <sub>O</sub> =2V to 8V, R <sub>L</sub> =10kΩ to 5V | 100  | 120  | -    | dB    |
| Common Mode Rejection Ratio     | CMR                  | V <sub>ICM</sub> =0V to 8.4V                         | 65   | 85   | -    | dB    |
| Supply Voltage Rejection Ratio  | SVR                  | V <sub>DD</sub> =4V to 16V                           | 70   | 85   | -    | dB    |
| Maximum Output Voltage 1        | V <sub>OH</sub> 1    | R <sub>L</sub> =10kΩ to 5V                           | 9.95 | 9.98 | -    | V     |
|                                 | V <sub>OL</sub> 1    |  | -    | 0.02 | 0.05 |       |
| Maximum Output Voltage 2        | V <sub>OH</sub> 2    | R <sub>L</sub> =10kΩ to 0V                           | 9.90 | 995  | -    | V     |
|                                 | V <sub>OL</sub> 2    |  | -    | 0.01 | 0.05 |       |
| Maximum Output Voltage 3        | V <sub>OH</sub> 3    | I <sub>source</sub> = 3mA                            | 9.70 | 9.80 | -    | V     |
|                                 | V <sub>OL</sub> 3    | I <sub>sink</sub> = 3mA                              | -    | 0.15 | 0.30 |       |
| Common Mode Input Voltage Range | V <sub>ICM</sub>     | CMR≥65dB   | 0    | -    | 8.4  | V     |

**● AC CHARACTERISTICS**

 (V<sub>DD</sub>=10V, V<sub>SS</sub>=0V, Ta=25°C, unless otherwise noted.)

| PARAMETER                      | SYMBOL          | TEST CONDITION   | MIN. | TYP.  | MAX. | UNIT   |
|--------------------------------|-----------------|--|------|-------|------|--------|
| Gain Bandwidth Product         | GBW             | R <sub>L</sub> =10kΩ to 5V, C <sub>L</sub> =20pF, f=1kHz   | -    | 80    | -    | kHz    |
| Phase Margin                   | φ <sub>M</sub>  | R <sub>L</sub> =10kΩ to 5V, C <sub>L</sub> =20pF   | -    | 75    | -    | deg    |
| Gain Margin                    | G <sub>M</sub>  | R <sub>L</sub> =10kΩ to 5V, C <sub>L</sub> =20pF   | -    | 23    | -    | dB     |
| Equivalent Input Noise Voltage | V <sub>NI</sub> | f=1kHz   | -    | 45    | -    | nV/√Hz |
| Channel Separation             | CS              | f=1kHz   | -    | 120   | -    | dB     |
| Slew Rate                      | SR1             | G <sub>V</sub> =0dB, R <sub>L</sub> =10kΩ to 5V, C <sub>L</sub> =20pF, V <sub>in</sub> =6Vpp (2V to 8V) (Note 4)                     | -    | 0.04  | -    | V/μs   |
|                                | SR2             | G <sub>V</sub> =0dB, R <sub>L</sub> =10kΩ to 0V, C <sub>L</sub> =20pF, V <sub>in</sub> =6Vpp (2V to 8V) (Note 4)                     | -    | 0.04  | -    |        |
| Power Band                     | PBW1            | G <sub>V</sub> =+6dB, R <sub>L</sub> =10kΩ to 5V, C <sub>L</sub> =20pF, V <sub>in</sub> =5Vpp (2.5V to 7.5V), V <sub>o</sub> >9.8Vpp | -    | 1.6   | -    | kHz    |
|                                | PBW2            | G <sub>V</sub> =+6dB, R <sub>L</sub> =10kΩ to 0V, C <sub>L</sub> =20pF, V <sub>in</sub> =5Vpp (2.5V to 7.5V), V <sub>o</sub> >9.8Vpp | -    | 1.6   | -    |        |
| Total Harmonic Distortion      | THD1            | G <sub>V</sub> =+6dB, R <sub>L</sub> =10kΩ to 5V, C <sub>L</sub> =20pF, f=100Hz, V <sub>out</sub> =5Vpp                              | -    | 0.03  | -    | %      |
|                                | THD2            | G <sub>V</sub> =+6dB, R <sub>L</sub> =10kΩ to 0V, C <sub>L</sub> =20pF, f=100Hz, V <sub>out</sub> =5Vpp                              | -    | 0.003 | -    | %      |

(Note 4) Slew rate is defined by the lower value of the rise or fall.

**■ ELECTRICAL CHARACTERISTICS**
**● DC CHARACTERISTICS**

 (V<sub>DD</sub>=15V, V<sub>SS</sub>=0V, Ta=25°C, unless otherwise noted.)

| PARAMETER                       | SYMBOL               | TEST CONDITION  | MIN.  | TYP.  | MAX. | UNIT  |
|---------------------------------|----------------------|---|-------|-------|------|-------|
| Supply Current                  | I <sub>DD</sub>      | No Signal   | -     | 66    | 136  | μA    |
| Input Offset Voltage            | V <sub>IO</sub>      | V <sub>IC</sub> = 0V, R <sub>S</sub> =50Ω               | -     | 1     | 4    | mV    |
| Input Offset Voltage Drift      | ΔV <sub>IO</sub> /ΔT | Ta = -40°C to +85°C                                     | -     | 2.7   | -    | μV/°C |
| Input Bias Current              | I <sub>B</sub>       | V <sub>IC</sub> = 0V, R <sub>S</sub> =50Ω               | -     | 1     | -    | pA    |
| Input Offset Current            | I <sub>IO</sub>      | V <sub>IC</sub> = 0V, R <sub>S</sub> =50Ω               | -     | 1     | -    | pA    |
| Large Signal Voltage Gain       | A <sub>V</sub>       | V <sub>O</sub> =2V to 13V, R <sub>L</sub> =10kΩ to 7.5V | 100   | 120   | -    | dB    |
| Common Mode Rejection Ratio     | CMR                  | V <sub>ICM</sub> =0V to 13.4V                           | 65    | 85    | -    | dB    |
| Supply Voltage Rejection Ratio  | SVR                  | V <sub>DD</sub> =4V to 16V                              | 70    | 85    | -    | dB    |
| Maximum Output Voltage 1        | V <sub>OH</sub> 1    | R <sub>L</sub> =10kΩ to 7.5V                            | 14.95 | 14.98 | -    | V     |
|                                 | V <sub>OL</sub> 1    |   | -     | 0.02  | 0.05 |       |
| Maximum Output Voltage 2        | V <sub>OH</sub> 2    | R <sub>L</sub> =10kΩ to 0V                              | 14.90 | 14.93 | -    | V     |
|                                 | V <sub>OL</sub> 2    |   | -     | 0.01  | 0.05 |       |
| Maximum Output Voltage 3        | V <sub>OH</sub> 3    | I <sub>source</sub> = 3mA                               | 14.70 | 14.85 | -    | V     |
|                                 | V <sub>OL</sub> 3    | I <sub>sink</sub> = 3mA                                 | -     | 0.15  | 0.30 |       |
| Common Mode Input Voltage Range | V <sub>ICM</sub>     | CMR≥65dB  | 0     | -     | 13.4 | V     |

**● AC CHARACTERISTICS**

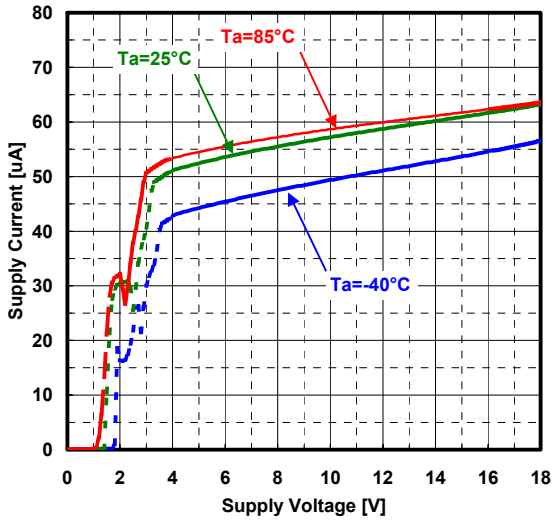
 (V<sub>DD</sub>=15V, V<sub>SS</sub>=0V, Ta=25°C, unless otherwise noted.)

| PARAMETER                      | SYMBOL          | TEST CONDITION   | MIN. | TYP.  | MAX. | UNIT   |
|--------------------------------|-----------------|--|------|-------|------|--------|
| Gain Bandwidth Product         | GBW             | R <sub>L</sub> =10kΩ to 7.5V, C <sub>L</sub> =20pF, f=1kHz   | -    | 90    | -    | kHz    |
| Phase Margin                   | φ <sub>M</sub>  | R <sub>L</sub> =10kΩ to 7.5V, C <sub>L</sub> =20pF   | -    | 75    | -    | deg    |
| Gain Margin                    | G <sub>M</sub>  | R <sub>L</sub> =10kΩ to 7.5V, C <sub>L</sub> =20pF   | -    | 23    | -    | dB     |
| Equivalent Input Noise Voltage | V <sub>NI</sub> | f=1kHz   | -    | 40    | -    | nV/√Hz |
| Channel Separation             | CS              | f=1kHz   | -    | 120   | -    | dB     |
| Slew Rate                      | SR1             | G <sub>V</sub> =0dB, R <sub>L</sub> =10kΩ to 7.5V, C <sub>L</sub> =20pF, V <sub>in</sub> =11Vpp (2V to 13V) (Note 4)                         | -    | 0.04  | -    | V/μs   |
|                                | SR2             | G <sub>V</sub> =0dB, R <sub>L</sub> =10kΩ to 0V, C <sub>L</sub> =20pF, V <sub>in</sub> =11Vpp (2V to 13V) (Note 4)                           | -    | 0.04  | -    |        |
| Power Band                     | PBW1            | G <sub>V</sub> =+6dB, R <sub>L</sub> =10kΩ to 7.5V, C <sub>L</sub> =20pF, V <sub>in</sub> =7.5Vpp (3.75V to 11.25V), V <sub>o</sub> >14.8Vpp | -    | 1.1   | -    | kHz    |
|                                | PBW2            | G <sub>V</sub> =+6dB, R <sub>L</sub> =10kΩ to 0V, C <sub>L</sub> =20pF, V <sub>in</sub> =7.5Vpp (3.75V to 11.25V), V <sub>o</sub> >14.8Vpp   | -    | 0.8   | -    |        |
| Total Harmonic Distortion      | THD1            | G <sub>V</sub> =+6dB, R <sub>L</sub> =10kΩ to 7.5V, C <sub>L</sub> =20pF, f=100Hz, V <sub>out</sub> =10Vpp                                   | -    | 0.02  | -    | %      |
|                                | THD2            | G <sub>V</sub> =+6dB, R <sub>L</sub> =10kΩ to 0V, C <sub>L</sub> =20pF, f=100Hz, V <sub>out</sub> =10Vpp                                     | -    | 0.003 | -    | %      |

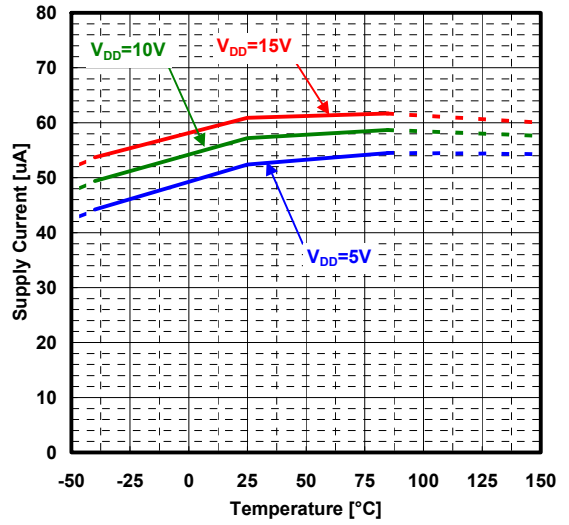
(Note 4) Slew rate is defined by the lower value of the rise or fall.

■ TYPICAL CHARACTERISTICS

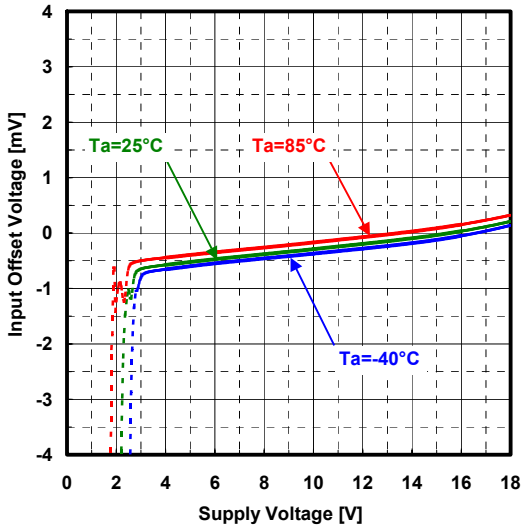
Supply Current vs. Supply Voltage  
 $V_{IC}=V_{DD}/2$



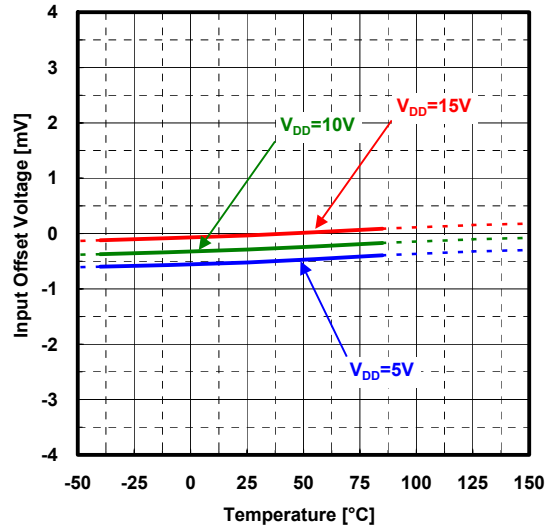
Supply Current vs. Temperature  
 $V_{IC}=V_{DD}/2$



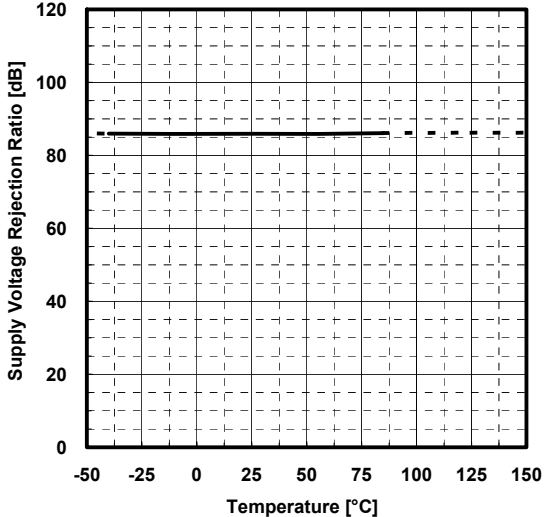
Input Offset Voltage vs. Supply Voltage  
 $V_{IC}=V_{DD}/2$



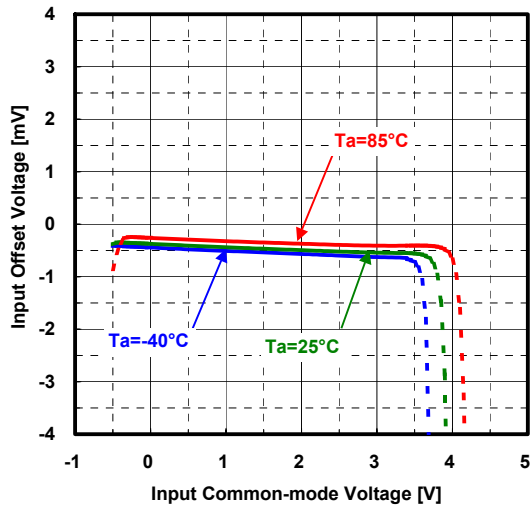
Input Offset Voltage vs. Temperature  
 $V_{IC}=V_{DD}/2$



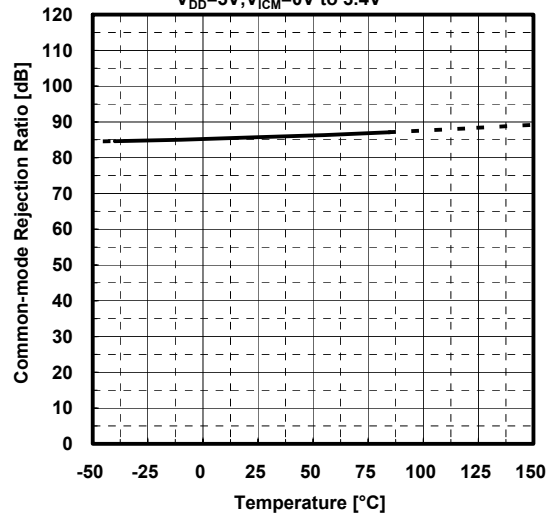
Supply Voltage Rejection Ratio vs. Temperature  
 $V_{DD}=4V \text{ to } 16V, V_{IC}=V_{DD}/2$



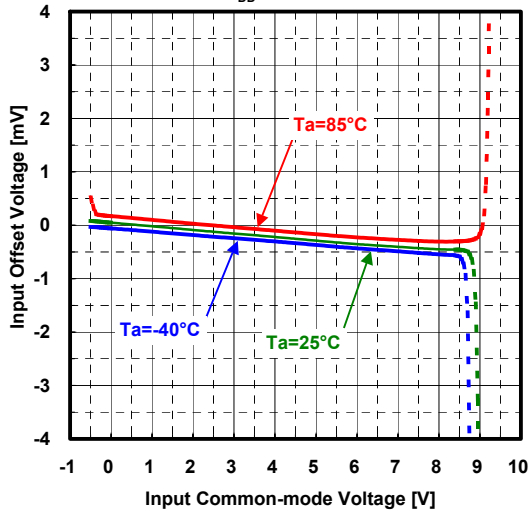
Input Offset Voltage vs. Input Common-mode Voltage  
 $V_{DD}=5V$



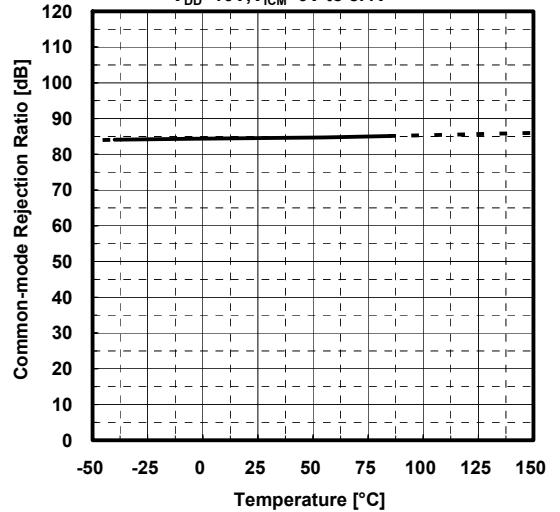
Common-mode Rejection Ratio vs. Temperature  
 $V_{DD}=5V, V_{ICM}=0V \text{ to } 3.4V$



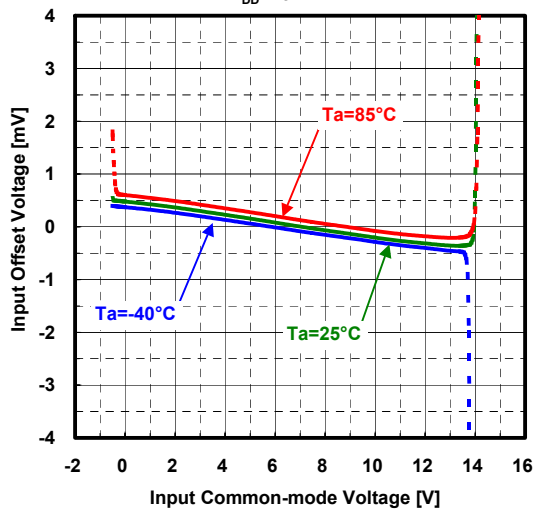
Input Offset Voltage vs. Input Common-mode Voltage  
 $V_{DD}=10V$



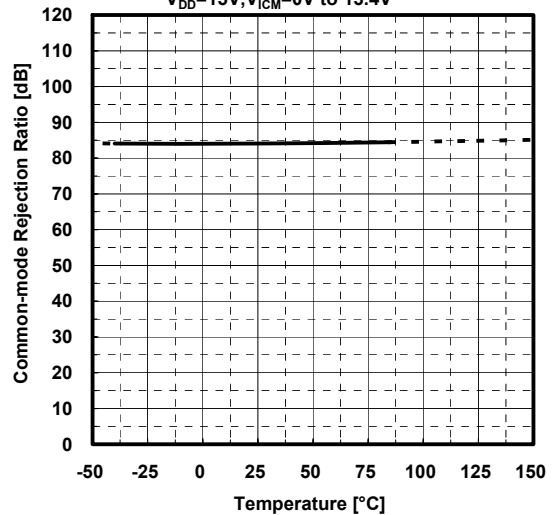
Common-mode Rejection Ratio vs. Temperature  
 $V_{DD}=10V, V_{ICM}=0V \text{ to } 8.4V$

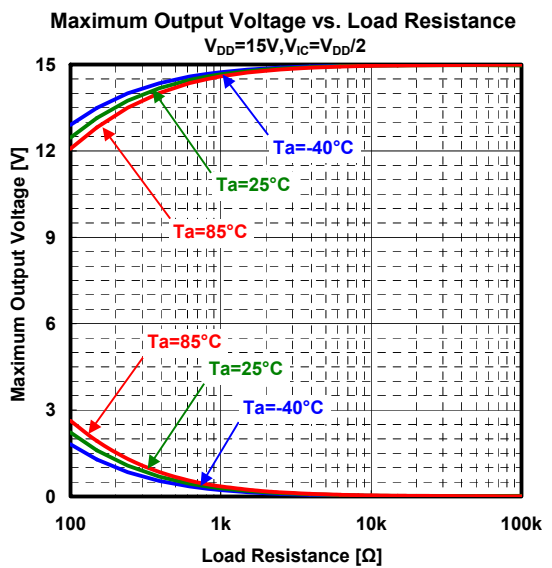
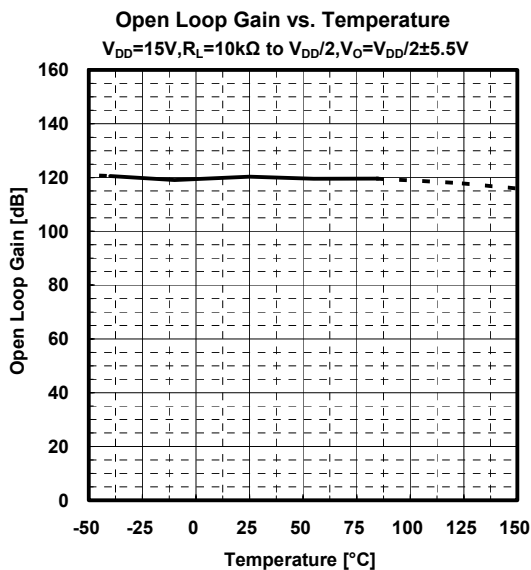
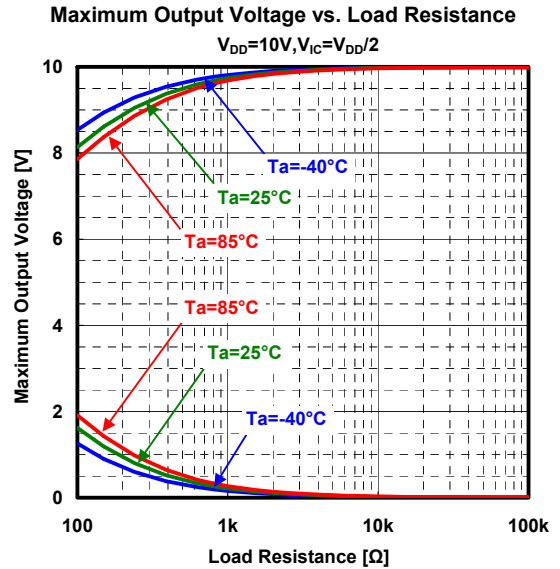
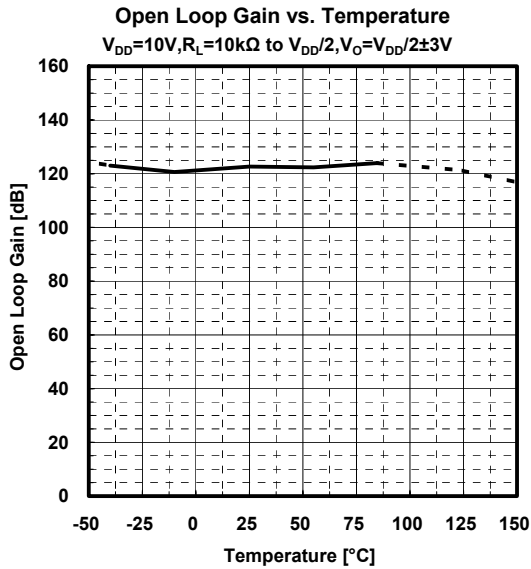
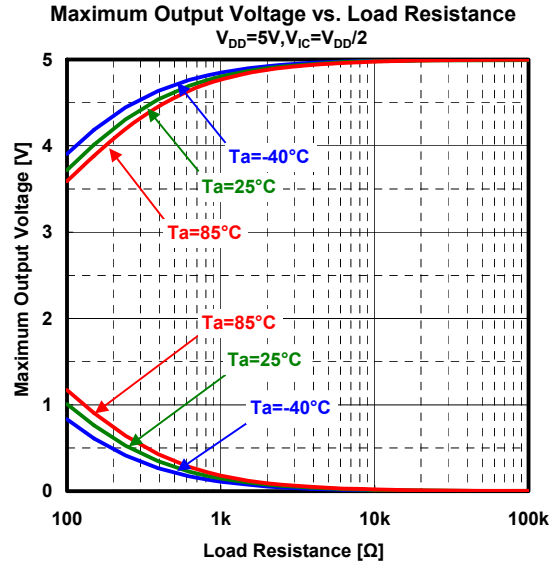
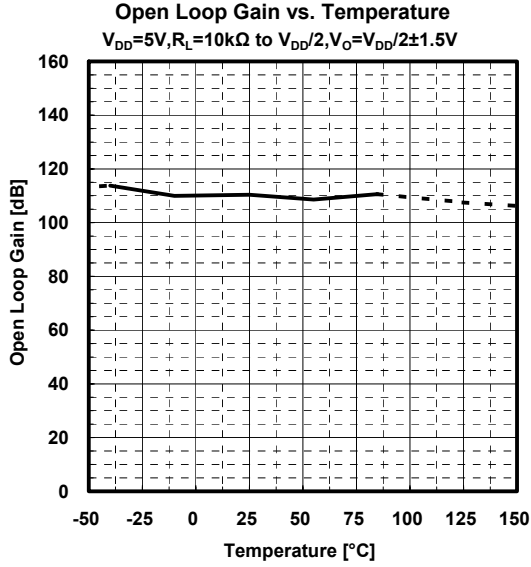


Input Offset Voltage vs. Input Common-mode Voltage  
 $V_{DD}=15V$

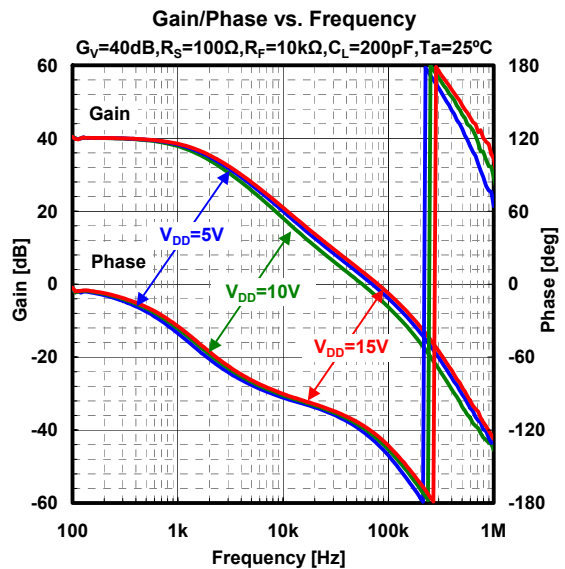
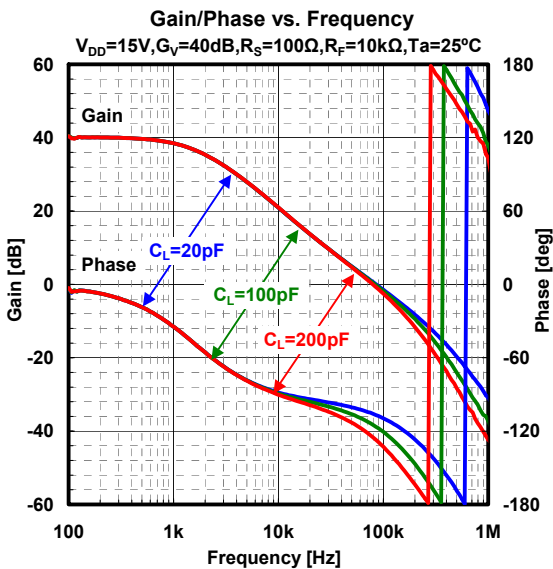
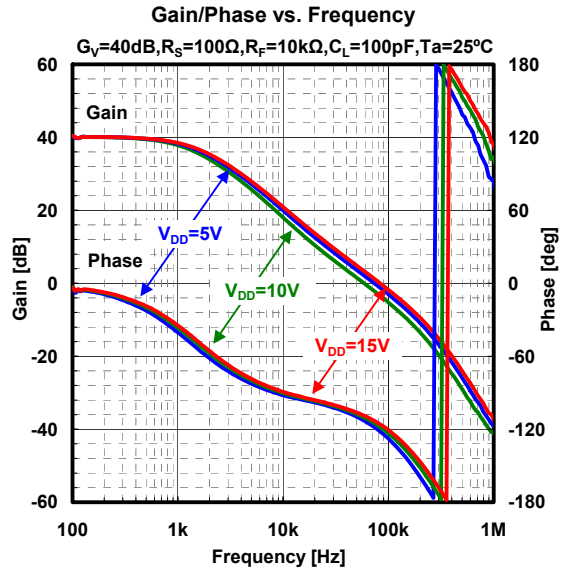
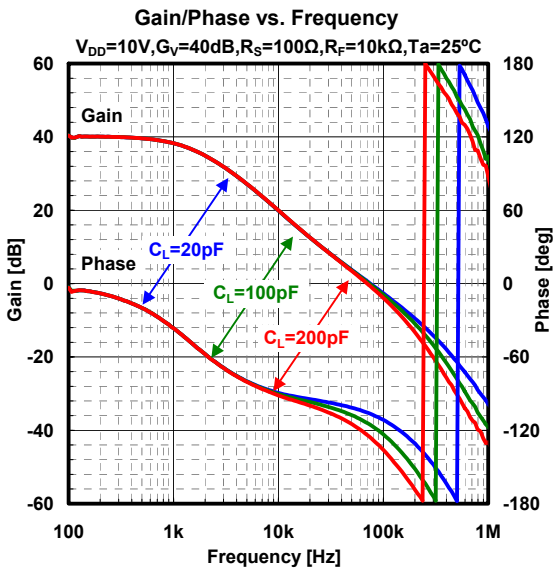
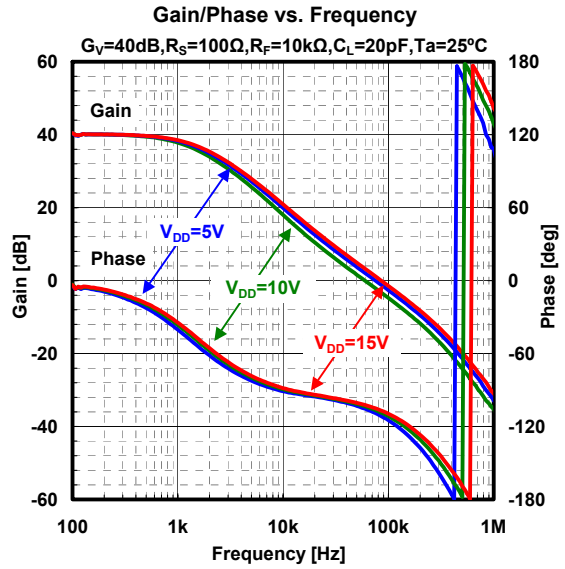
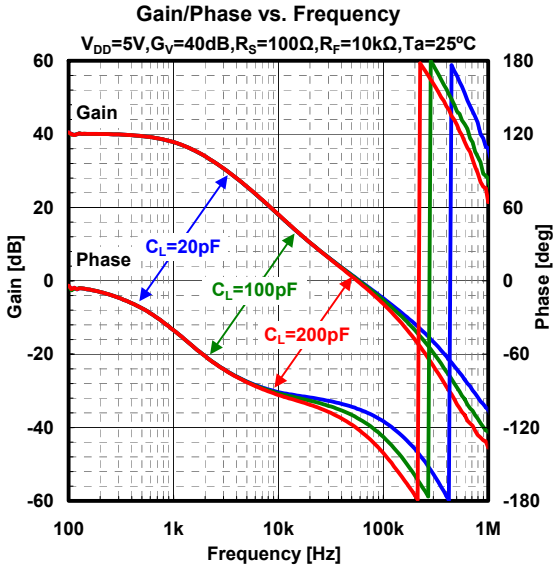


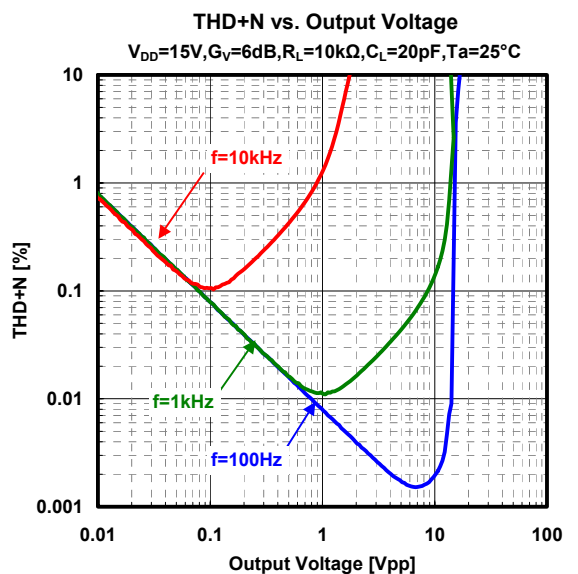
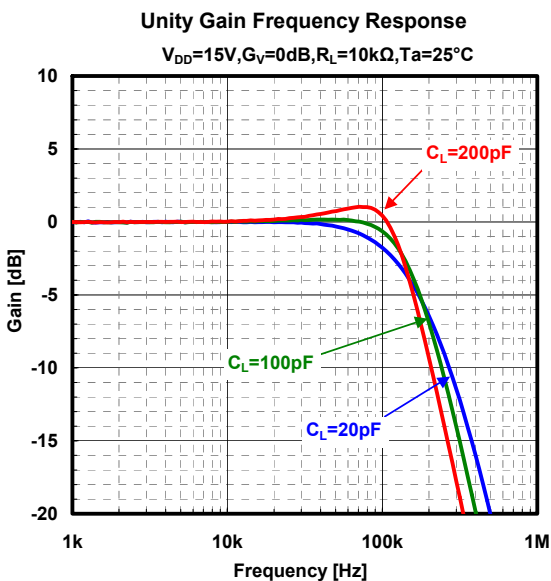
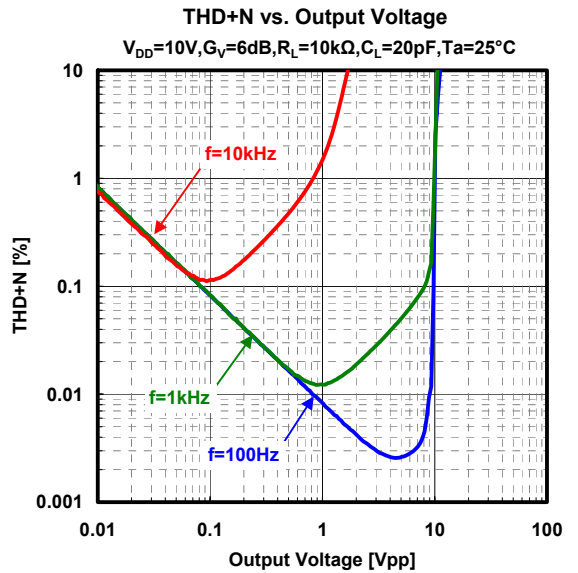
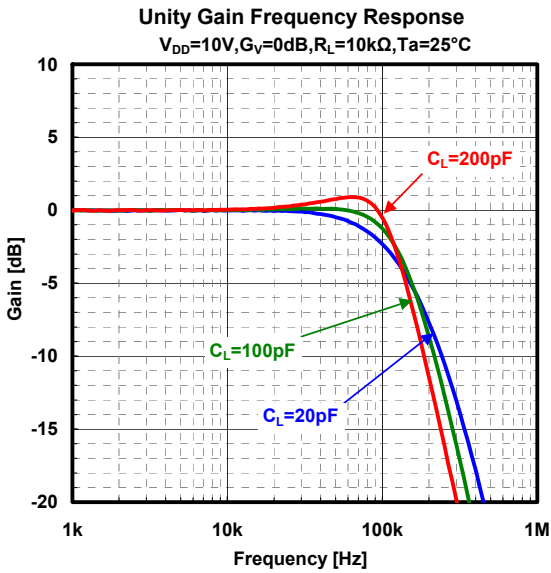
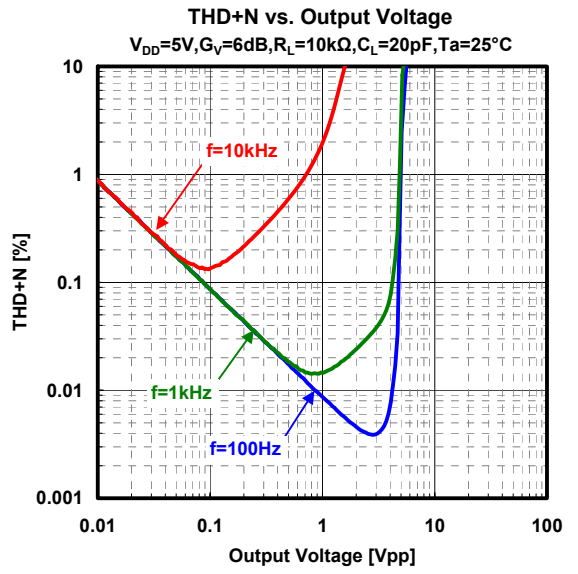
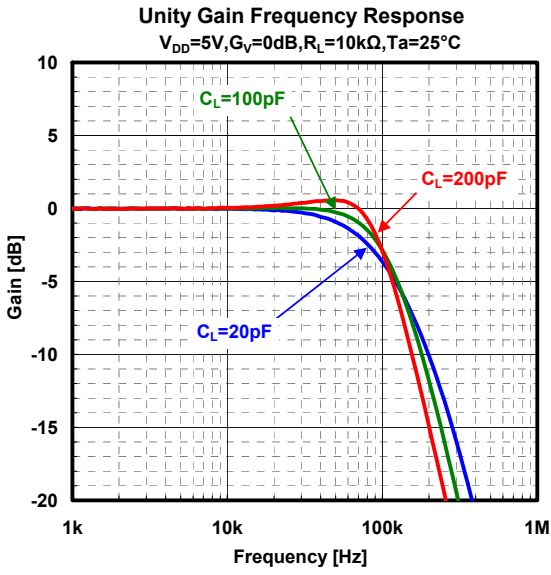
Common-mode Rejection Ratio vs. Temperature  
 $V_{DD}=15V, V_{ICM}=0V \text{ to } 13.4V$





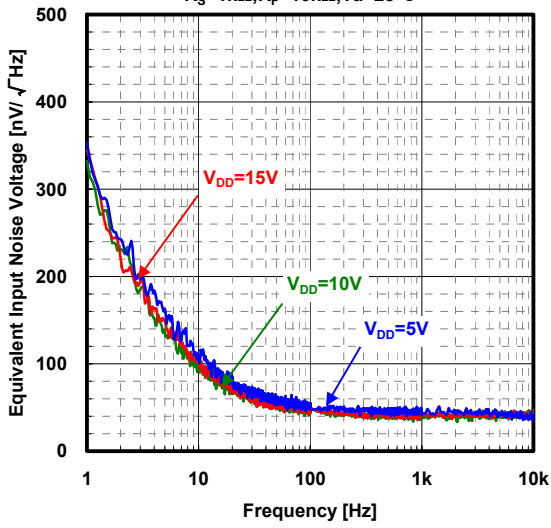






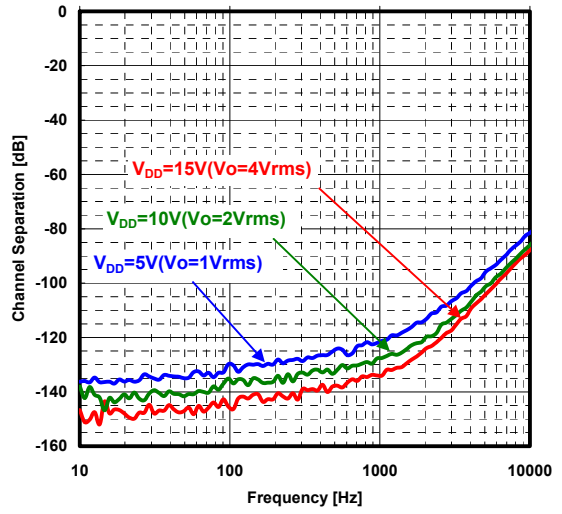
Equivalent Input Noise Voltage

$R_S=1k\Omega, R_F=10k\Omega, T_a=25^\circ C$



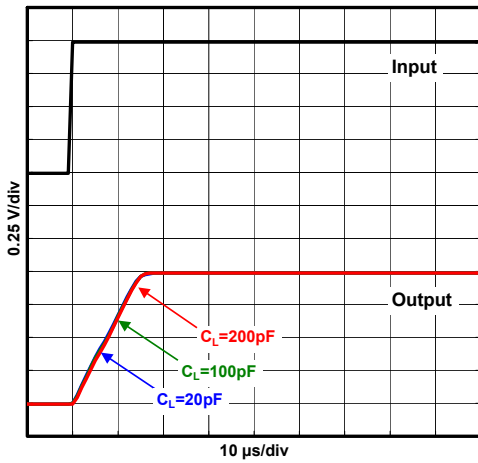
Channel Separation vs. Frequency

$R_S=1k\Omega, R_F=100k\Omega, R_T=1k\Omega, R_L=open, T_a=25^\circ C$



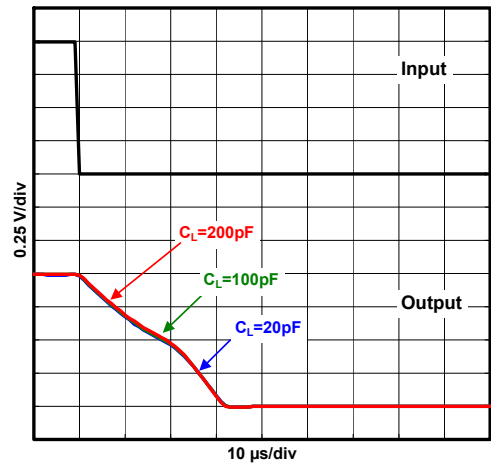
Transient Response

$V_{DD}=5V, G_V=0dB, V_{IN}=1V_{PP}, R_L=10k\Omega, T_a=25^\circ C$



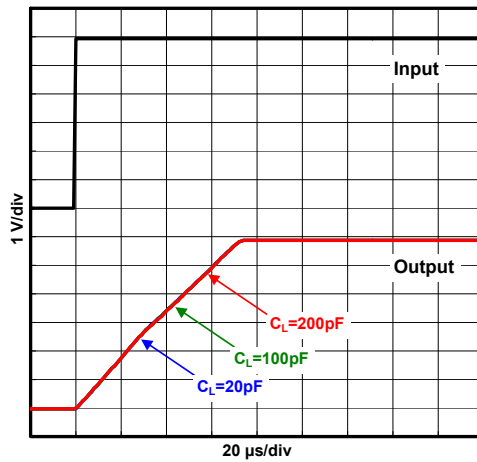
Transient Response

$V_{DD}=5V, G_V=0dB, V_{IN}=1V_{PP}, R_L=10k\Omega, T_a=25^\circ C$



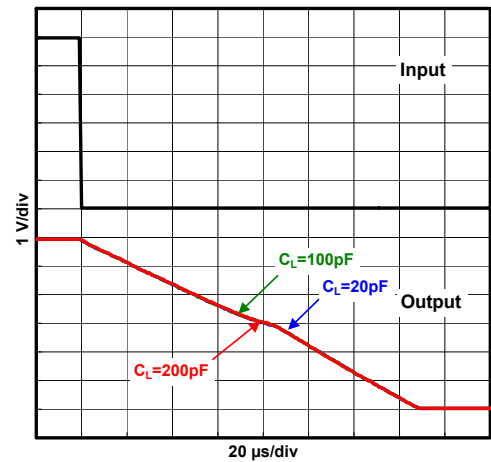
Transient Response

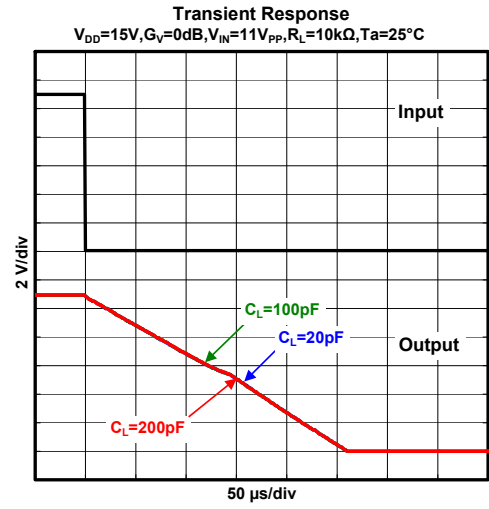
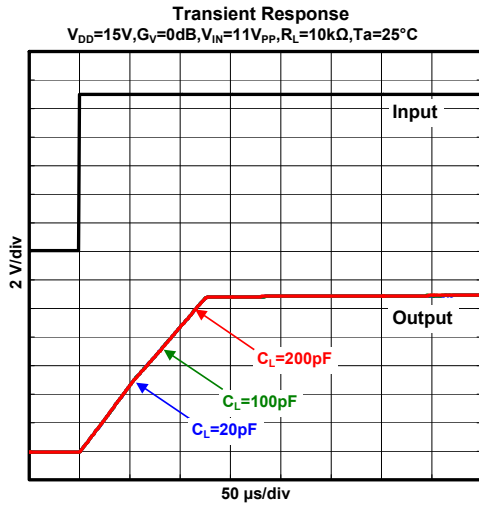
$V_{DD}=10V, G_V=0dB, V_{IN}=6V_{PP}, R_L=10k\Omega, T_a=25^\circ C$



Transient Response

$V_{DD}=10V, G_V=0dB, V_{IN}=6V_{PP}, R_L=10k\Omega, T_a=25^\circ C$





[CAUTION]  
 The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.